

Transistor

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	–	–	±10	μA	V _{GS} =±20V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR)DSS}	–45	–	–	V	I _D =–1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	–	–	–1	μA	V _{DS} =–45V, V _{GS} =0V
Gate threshold voltage	V _{GS(th)}	–1.0	–	–2.5	V	V _{DS} =–10V, I _D =–1mA
Static drain-source on-state resistance	R _{DS(on)} ¹⁾	–	19	27	mΩ	I _D =–7A, V _{GS} =–10V
		–	25	35	mΩ	I _D =–7A, V _{GS} =–4.5V
		–	28	39	mΩ	I _D =–7A, V _{GS} =–4.0V
Forward transfer admittance	Y _{fs} ²⁾	10.0	–	–	S	V _{DS} =–10V, I _D =–7A
Input capacitance	C _{iss}	–	4100	–	pF	V _{DS} =–10V
Output capacitance	C _{oss}	–	510	–	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	–	330	–	pF	f=1MHz
Turn-on delay time	t _{d(on)} ³⁾	–	31	–	ns	V _{DD} =–25V
Rise time	t _r ⁴⁾	–	35	–	ns	I _D =–3.5A
Turn-off delay time	t _{d(off)} ⁵⁾	–	135	–	ns	V _{GS} =–10V
Fall time	t _f ⁶⁾	–	50	–	ns	R _L =–7Ω
Total gate charge	Q _g ⁷⁾	–	34.0	47.6	nC	R _E =10Ω
Gate-source charge	Q _{gs} ⁸⁾	–	9.5	–	nC	V _{DD} =–25V V _{GS} =–5V
Gate-drain charge	Q _{gd} ⁹⁾	–	12	–	nC	I _D =–7A
						R _L =3.5Ω R _E =10Ω

¹⁾Pulsed

Body diode characteristics (Source-Drain)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _{SD} [*]	–	–	–1.2	V	I _S =–7A, V _{GS} =0V

^{*}Pulsed

Transistor

●Electrical characteristic curves

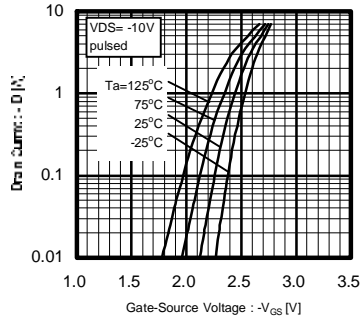


Fig.1 Typical Transfer Characteristics

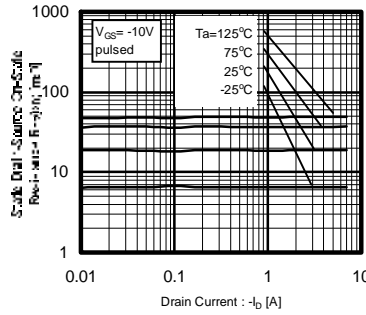


Fig.2 Static Drain-Source On-State Resistance vs. Drain Current (1)

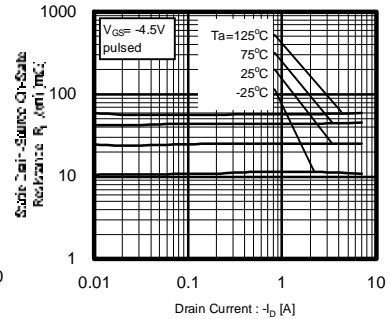


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current (2)

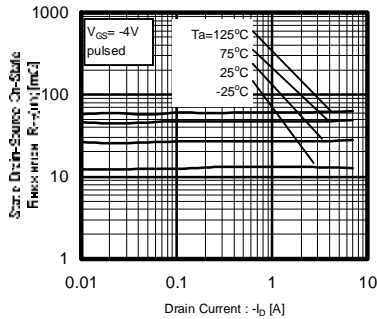


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current (3)

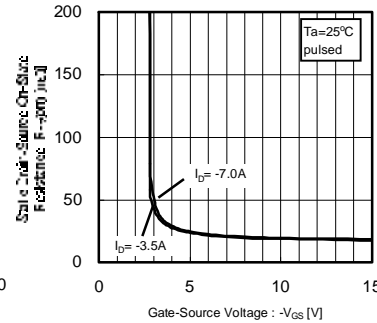


Fig.5 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

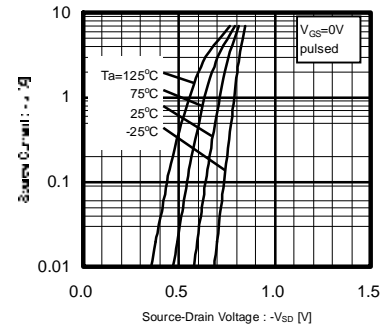


Fig.6 Source-Current vs. Source-Drain Voltage

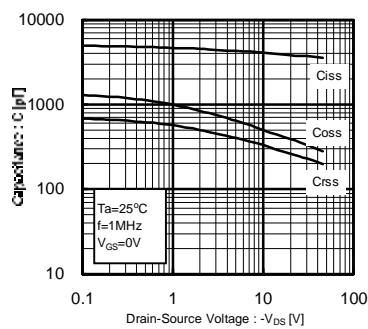


Fig.7 Typical capacitance vs. Source-Drain Voltage

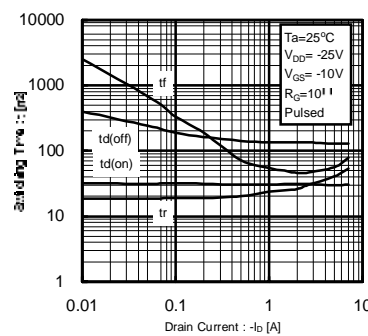


Fig.8 Switching Characteristics

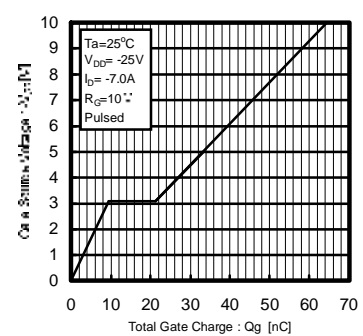


Fig.9 Dynamic Input Characteristics

Transistor

●Measurement circuits

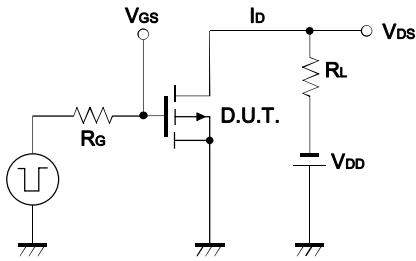


Fig.10 Switching Time Test Circuit

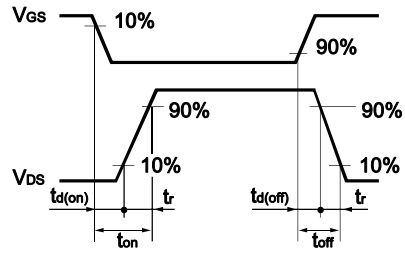


Fig.11 Switching Time Waveforms

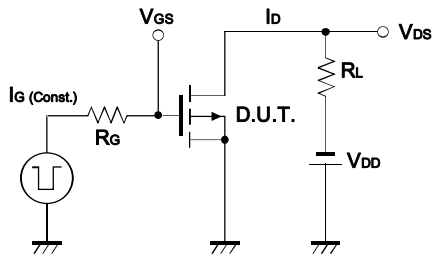


Fig.12 Gate Charge Test Circuit

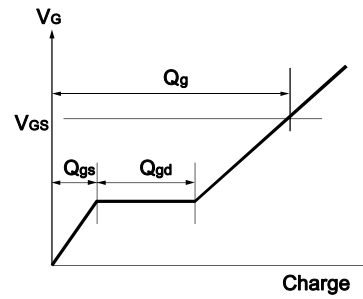


Fig.13 Gate Charge Waveform

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